

MOSFETs Silicon N-Channel MOS (DTMOSVI)

# TK190U65Z

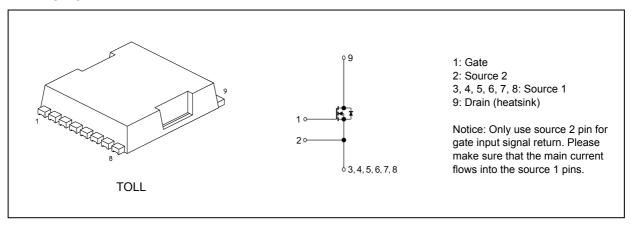
#### 1. Applications

· Switching Power Supplies

#### 2. Features

- (1) Low drain-source on-resistance:  $R_{DS(ON)} = 0.149 \Omega$  (typ.)
- (2) High-speed switching properties with the lower capacitance.
- (3) Enhancement mode:  $V_{th} = 3$  to  $4 \text{ V} (V_{DS} = 10 \text{ V}, I_D = 0.61 \text{ mA})$

### 3. Packaging and Internal Circuit



# 4. Absolute Maximum Ratings (Note) (Ta = 25 °C unless otherwise specified)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		$V_{DSS}$	650	V
Gate-source voltage		V <sub>GSS</sub>	±30	
Drain current (DC)	(Note 1)	I <sub>D</sub>	15	Α
Drain current (pulsed)	(Note 1)	I <sub>DP</sub>	60	
Power dissipation (T	T <sub>c</sub> = 25 °C)	P <sub>D</sub>	130	W
Single-pulse avalanche energy	(Note 2)	E <sub>AS</sub>	165	mJ
Single-pulse avalanche current		I <sub>AS</sub>	3.7	Α
Reverse drain current (DC)	(Note 1)	I <sub>DR</sub>	15	1
Reverse drain current (pulsed)	(Note 1)	I <sub>DRP</sub>	60	
Channel temperature		T <sub>ch</sub>	150	°C
Storage temperature		T <sub>stg</sub>	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

1

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production



### 5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	R <sub>th(ch-c)</sub>	0.961	°C/W

Note 1: Ensure that the channel temperature does not exceed 150  $^{\circ}\text{C}.$ 

Note 2:  $V_{DD}$  = 90 V,  $T_{ch}$  = 25 °C (initial), L = 21.4 mH,  $I_{AS}$  = 3.7 A

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.



#### 6. Electrical Characteristics

# 6.1. Static Characteristics (T<sub>a</sub> = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I <sub>GSS</sub>	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±1	μΑ
Drain cut-off current	I <sub>DSS</sub>	V <sub>DS</sub> = 650 V, V <sub>GS</sub> = 0 V	_	_	2	
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V	650	_	_	V
Gate threshold voltage	V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 0.61 mA	3	_	4	
Drain-source on-resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 7.5 A	_	0.149	0.19	Ω

# 6.2. Dynamic Characteristics (T<sub>a</sub> = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 300 V, V <sub>GS</sub> = 0 V, f = 100 kHz	_	1370	_	pF
Reverse transfer capacitance	C <sub>rss</sub>		_	1.5	_	
Output capacitance	C <sub>oss</sub>		_	34	_	
Effective output capacitance	C <sub>o(er)</sub>	V <sub>DS</sub> = 0 to 400 V, V <sub>GS</sub> = 0 V	_	53	_	
Gate resistance	r <sub>g</sub>	V <sub>DS</sub> = OPEN , f = 1 MHz	_	3	_	Ω
Switching time (rise time)	t <sub>r</sub>	See Figure 6.2.1	_	14	_	ns
Switching time (turn-on time)	t <sub>on</sub>		_	34	_	
Switching time (fall time)	t <sub>f</sub>		_	4	_	
Switching time (turn-off time)	t <sub>off</sub>		_	66	_	
MOSFET dv/dt ruggedness	dv/dt	$V_{DS} \le V_{(BR)DSS}, I_D \le 7.5 A$	70	_	-	V/ns

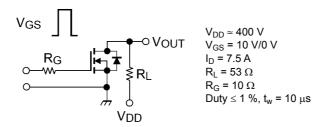


Fig. 6.2.1 Switching Time Test Circuit

# 6.3. Gate Charge Characteristics (T<sub>a</sub> = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	$Q_g$	$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 15 \text{ A}$		25		nC
Gate-source charge 1	Q <sub>gs1</sub>			7.9		
Gate-drain charge	$Q_{gd}$		_	7.1	_	

# 6.4. Source-Drain Characteristics (T<sub>a</sub> = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Diode forward voltage	$V_{DSF}$	I <sub>DR</sub> = 15 A, V <sub>GS</sub> = 0 V	_	_	-1.7	V
Reverse recovery time		V <sub>DD</sub> = 400 V,	_	270	_	ns
Reverse recovery charge	$Q_{rr}$	I <sub>DR</sub> = 7.5 A, V <sub>GS</sub> = 0 V -dI <sub>DR</sub> /dt = 100 A/μs	_	3.0	_	μС
Peak reverse recovery current	I <sub>rr</sub>	-αι <sub>DR</sub> /αι – 100 Α/μ3	_	22	_	Α
Diode dv/dt ruggedness	dv/dt	$V_{DD} \le 400 \text{ V}, I_{DR} \le 7.5 \text{ A}, V_{GS} = 0 \text{ V}$	40	_	_	V/ns



# 7. Marking

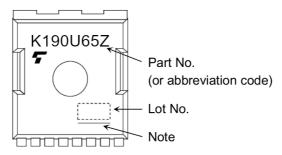


Fig. 7.1 Marking



### 8. Characteristics Curves (Note)

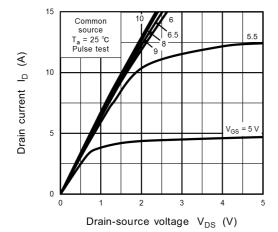
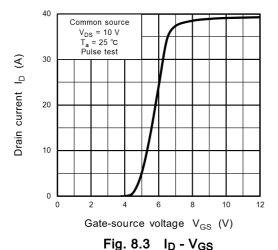


Fig. 8.1 I<sub>D</sub> - V<sub>DS</sub>



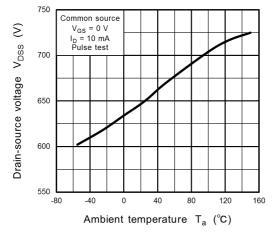


Fig. 8.5 V<sub>DSS</sub> - T<sub>a</sub>

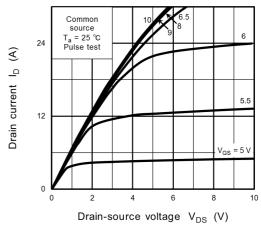


Fig. 8.2 I<sub>D</sub> - V<sub>DS</sub>

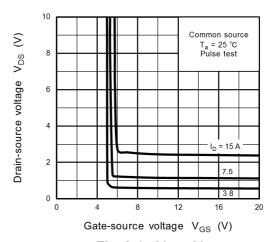


Fig. 8.4 VDS - VGS

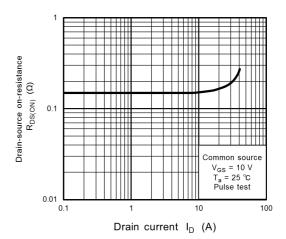
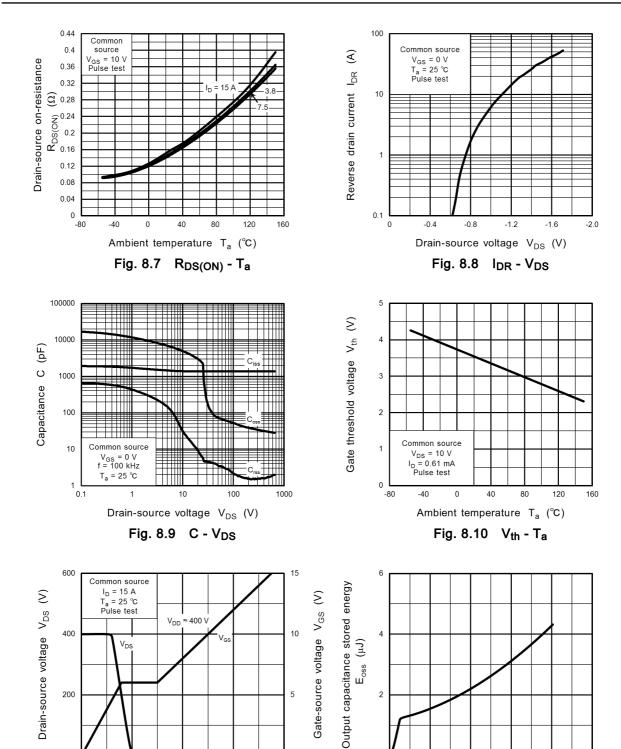


Fig. 8.6 R<sub>DS(ON)</sub> - I<sub>D</sub>





 $\begin{tabular}{lll} Total gate charge & Q_g & (nC) \\ \hline \end{tabular} \begin{tabular}{lll} Fig. 8.11 & Dynamic Input/Output Characteristics \\ \hline \end{tabular}$ 

20

Drain-source voltage  $V_{DS}$  (V) Fig. 8.12 Eoss -  $V_{DS}$ 

0

0

Rev.1.0

40



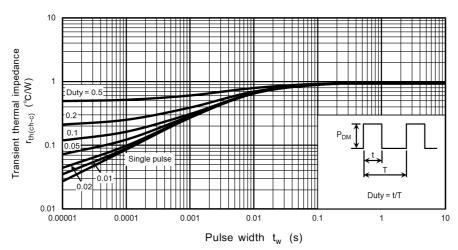


Fig. 8.13 rth - tw (Guaranteed Maximum)

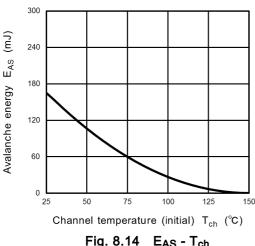


Fig. 8.14 EAS - Tch (Guaranteed Maximum)

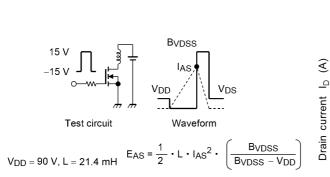


Fig. 8.16 Test Circuit/Waveform

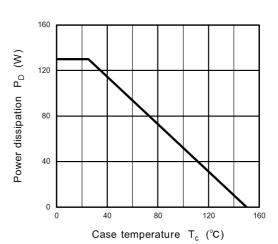


Fig. 8.15 P<sub>D</sub> - T<sub>c</sub> (Guaranteed Maximum)

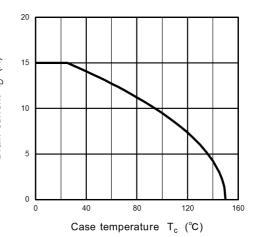


Fig. 8.17 I<sub>D</sub> - T<sub>c</sub> (Guaranteed Maximum)



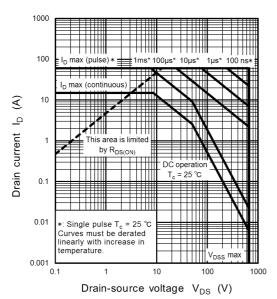


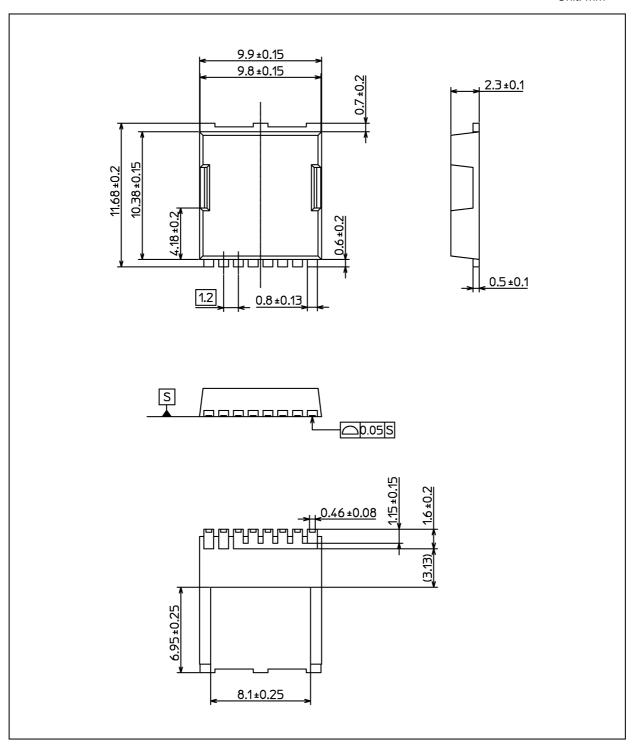
Fig. 8.18 Safe Operating Area (Guaranteed Maximum)

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



# **Package Dimensions**

Unit: mm



Weight: 0.75 g (typ.)

Package Name(s)
TOSHIBA: 2-10AF1A
Nickname: TOLL



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